



高速光耦

High Speed Photo Coupler

QX06XX

宁波群芯微电子股份有限公司

NINGBO QUNXIN MICROELECTRONICS CO., LTD.

中国 浙江省宁波杭州湾新区玉海东路 68 号

68 Yuhaidong Road, Hangzhou Bay New District, Ningbo, Zhejiang, China

概述 Description

QX0601、QX0611 光耦合器由一个 850nm 的 AlGaAs LED 组成，其光学耦合到一个非常高速的集成光电探测器逻辑门，可快速输出。

The QX0601 QX0611 optocoupler consists of a 850 nm AlGaAs LED, optically coupled to a very high speed integrated photodetector logic gate for fast output.

特性 Features

- 高比特率：10Mbit/s
High bit rate: 10Mbit/s
- 输入-输出隔离电压 ($V_{ISO}=3750$ Vrms)
High isolation voltage between input and output ($V_{ISO}=3750$ Vrms)
- 工作温度范围：-40°C ~ +105°C
Operating Temperature: -40°C to +105°C
- 逻辑门输出
Logic gate output
- 符合加强绝缘标准
Meet reinforced insulation standards
- 符合安规标准：UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022
Meet Safety standard : UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022

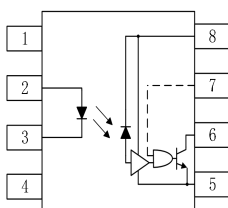
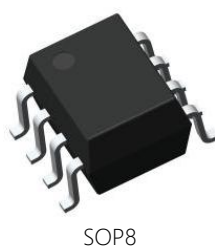
应用 Applications

- 接地回路消除
Ground loop elimination
- LSTTL 转 TTL, LSTTL 或 5V CMOS
LSTTL to TTL, LSTTL or 5-volt CMOS
- 线路接收器，数据传输
Line receiver, data transmission
- 开关电源
Switching power supplies
- 计算机外围接口
Computer-peripheral interface

真值表 Truth table

LED	ENABLE	OUT
ON	H	L
OFF	H	H
ON	L	H
OFF	L	H
ON	NC	L
OFF	NC	H

封装和原理图 Package and Schematic Diagram



Pin Configuration

1.NC	8.VCC
2. Anode	7.VE
3. Cathode	6.VO
4. NC	5.GND

注：在引脚 5 和 8 之间必须连接一个 0.1uF 的旁路电容器。

Note: 0.1uF bypass capacitor must be connected between pins 5 and 8.

产品型号命名规则 Order Code

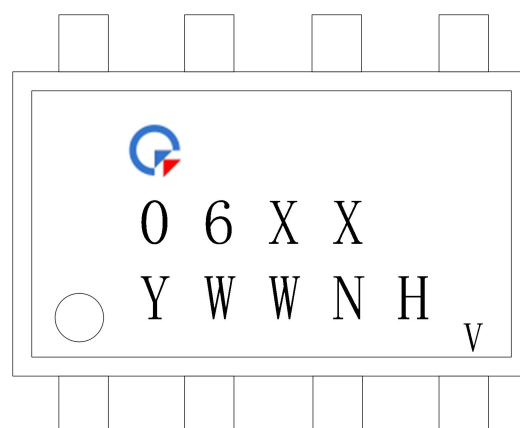
QX 06XX - UN Y - W (V) (ZZ)

① ② ③ ④ ⑤ ⑥ ⑦

- ① 公司代码 Company Code (QX: 群芯 Qunxin)
- ② 产品系列 Product Series (XX:01, 11)
- ③ 框架类型 Lead Frame (Cu: 铜框架 Copper)
- ④ 树脂类型 Epoxy Type (H: 无卤 Halogen-free)
- ⑤ 封装形式 Package (S: SOP)
- ⑥ 器件工作温度范围 Device Operating Temperature Range (特殊范围需填或者空白 Special Range need to be filled in or left blank)
- ⑦ 内部补充代码 Internal Supplementary Code (数字或者空白 Number or None)

印字信息 Marking Information

- 印字中“”为群芯品牌 LOGO
“”denotes LOGO
- 印字中的“XX”代表产品分档: 01、11
“XX”denotes the classification: 01、11
- 印字中“Y”代表年份; A(2018),B(2019),C(2020).....
“Y”denotes YEAR: A(2018), B(2019), C(2020).....
- 印字中“WW”代表周号
“WW”denotes week's number
- 印字中“N”代表星期几
“N”denotes day of the week
- 印字中的“H”代表无卤
“H”denotes Halogen-free
- 印字中的“V”代表产品特殊标识: A~Z 或空白
“V”denotes Product special code: A~Z or None



绝缘和安规信息 Insulation and Safety related specifications

项目 Item	符号 Symbol	数值 Value	单位 Unit	备注 Remark
爬电距离 Creepage Distance	L	> 4.6	mm	从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body
电气间隙 Clearance Distance	L	> 4.6	mm	从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air
绝缘距离 Insulation Thickness	DTI	> 0.4	mm	发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector
峰值隔离电压 Peak Isolation Voltage	V_{IORM}	600	V_{peak}	DIN/EN/DIN EN60747-5-5
瞬态隔离电压 Transient isolation voltage	V_{IOTM}	5000	V_{peak}	DIN/EN/DIN EN60747-5-5
隔离电压 Isolation Voltage	V_{iso}	> 3750	V_{rms}	For 1 min

极限参数 Absolute Maximum Ratings ($T_A=25^{\circ}C$)

参数 Parameter		符号 Symbol	额定值 Rating	单位 Unit
发射端 Input	正向电流 Forward Current	I_F	50	mA
	使能输入电压不超过 V_{CC} 500mV Enable Input Voltage Not to Exceed V_{CC} by more than 500mV	V_E	5.5	V
	反向电压 Reverse Voltage	V_R	5	V
	输入功耗 Input Power Dissipation	P_I	100	mW
接收端 output	电源电压 Supply Voltage	V_{CC}	7	V
	输出电流 Output Current	I_O	50	mA
	输出电压 Output Voltage	V_O	7	V
	输出集电极功耗 Output Collector Power Dissipation	P_O	85	mW
工作温度 Operating Temperature		T_{opr}	-40 to +105	$^{\circ}C$
存储温度 Storage Temperature		T_{stg}	-55 to +125	$^{\circ}C$
焊接温度 Soldering Temperature		T_{sol}	260	$^{\circ}C$

推荐操作条件 Recommended Operating Conditions

参数 Parameter	符号 Symbol	最小值 Min	最大值 Max.	单位 Unit
低电平输入电流 Low Level Input Current	I_{FL}	0	250	μA
高电平输入电流 High Level Input Current	I_{FH}	6.3	15	mA
电源电压 Supply Voltage	V_{CC}	3	5.5	V
低电平使能电压 Low Level Enable Voltage	V_{EL}	0	0.8	V
高电平使能电压 Low Level Enable Voltage	V_{EH}	2.0	V_{CC}	V
工作温度 Operating Temperature	T_A	-40	+105	$^{\circ}C$
输出上拉电阻 Output Pull-up Resistor	R_L	330	4k	Ω

产品特性参数 Electro-optical Characteristics ($T_A=25^{\circ}\text{C}$)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit
发射端 Input	正向电压 Input Forward Voltage	V_F	$I_F=10\text{mA}$	-	1.33	1.75	V
	反向击穿电压 Input Reverse Breakdown Voltage	B_{VR}	$I_R=10\mu\text{A}$	5	-	-	V
	输入电容 Input Capacitance	C_{IN}	$V=0, f=1\text{MHz}$	-	70	-	pF
	正向电压的温度系数 Input Diode Temperature Coefficient	$\Delta V_F/\Delta T_A$	$I_F=10\text{mA}$	-	-1.4	-	mV/ $^{\circ}\text{C}$
接收端 Output	高电平电源电流 High Level Supply Current	I_{CCH}	$I_F=0\text{mA}$ $V_{CC}=5.5\text{V}$ $V_E=0.5\text{V}$	-	6.5	10	mA
	低电平电源电流 Low Level Supply Current	I_{CCL}	$I_F=10\text{mA}$ $V_{CC}=5.5\text{V}$	-	9	13	mA
传输特性 Transfer Characteristics	低电平使能电流 Low Level Enable Current	I_{EL}	$V_{CC}=5.5\text{V}$ $V_E=0.5\text{V}$	-	-0.8	-1.6	mA
	高电平使能电流 High Level Enable Current	I_{EH}	$V_{CC}=5.5\text{V}$ $V_E=2.0\text{V}$	-	-0.6	-1.6	mA
	高电平使能电压 High Level Enable Voltage	V_{EH}	$I_F=10\text{mA}$ $V_{CC}=5.5\text{V}$	2.0	-	-	V
	低电平使能电压 Low Level Enable Voltage	V_{EL}	$I_F=10\text{mA}$ $V_{CC}=5.5\text{V}$	-	-	0.8	V
	高电平输出电流 High Level Output Current	I_{OH}	$I_F=250\mu\text{A}$ $V_{CC}=V_O=5.5\text{V}$ $V_E=2\text{V}$	-	-	100	μA
	低电平输出电压 Low Level Output Voltage	V_{OL}	$I_F=5\text{mA}$ $V_{CC}=5.5\text{V}$ $I_{OL}=13\text{mA}$ $V_E=2\text{V}$	-	0.35	0.6	V
	输入阈值电流 Input Threshold Current	I_{FT}	$V_{CC}=5.5\text{V}$ $I_{OL}=13\text{mA}$ $V_O<0.6\text{V}$ $V_E=2\text{V}$	-	3	5	mA
隔离电压 Isolation Voltage		V_{ISO}	$R_H<50\%$ $I_{I-O}\leq 50\mu\text{A}$	3750	-	-	V_{RMS}
隔离电阻 Isolation Resistance		R_{I-O}	$V_{I-O}=500\text{V}$	10^{12}	-	-	Ω
隔离电容 Isolation Capacitance		C_{I-O}	$V=0, f=1\text{MHz}$	-	0.6	-	pF

开关特性 Switching Specification ($T_A=25^{\circ}\text{C}$)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit
输出高电平传播延迟 Propagation Delay Time to Output High Level		T_{PLH}	$I_F=7.5\text{mA}$ $V_{CC}=5.0\text{V}$ $C_L=15\text{pF}$ $R_L=350\Omega$	20	41	75	ns
输出低电平传播延迟 Propagation Delay Time to Output Low Level		T_{PHL}		20	50	75	ns
脉宽失真 ($ T_{PHL}-T_{PLH} $) Pulse Width Distortion ($ T_{PHL}-T_{PLH} $)		PWD		-	5	35	ns
输出上升时间(10% – 90%) Output Rise Time (10–90%)		t_r		-	30	-	ns
输出下降时间(90% - 10%) Output Rise Time (90–10%)		t_f		-	10	-	ns
输出高电平使能传播延迟 Enable Propagation Delay Time to Output High Level		t_{ELH}	$I_F=7.5\text{mA}$ $V_{CC}=5.0\text{V}$ $V_{EH}=3.5\text{V}$ $C_L=15\text{pF}$ $R_L=350\Omega$	-	15	-	ns
输出低电平使能传播延迟 Enable Propagation Delay Time to Output Low Level		t_{EHL}		-	40	-	ns
输出高电平共模瞬态抑制 Common Mode Transient Immunity (at Output High Level)	0601	$ CM_H $	$I_F=0\text{mA}$, $V_{CC}=5.0\text{V}$ $ V_{CM} =50\text{V(Peak)}$ $V_{O(MIN)}=2.0\text{V}$, $R_L=350\Omega$	5	10	-	kV/ μs
	0611		$I_F=0\text{mA}$, $V_{CC}=5.0\text{V}$ $ V_{CM} =1000\text{V(Peak)}$ $V_{O(MIN)}=2.0\text{V}$, $R_L=350\Omega$	20	-	-	
输出低电平共模瞬态抑制 Common Mode Transient Immunity (at Output Low Level)	0601	$ CM_L $	$I_F=7.5\text{mA}$, $V_{CC}=5.0\text{V}$ $ V_{CM} =50\text{V(Peak)}$ $V_{O(MAX)}=0.8\text{V}$, $R_L=350\Omega$	5	10	-	kV/ μs
	0611		$I_F=7.5\text{mA}$, $V_{CC}=5.0\text{V}$ $ V_{CM} =1000\text{V(Peak)}$ $V_{O(MAX)}=0.8\text{V}$, $R_L=350\Omega$	20	-	-	

典型光电特性曲线 Typical Electro-Optical Characteristics Curves

Fig.1 Low-level output voltage vs. Ambient temperature

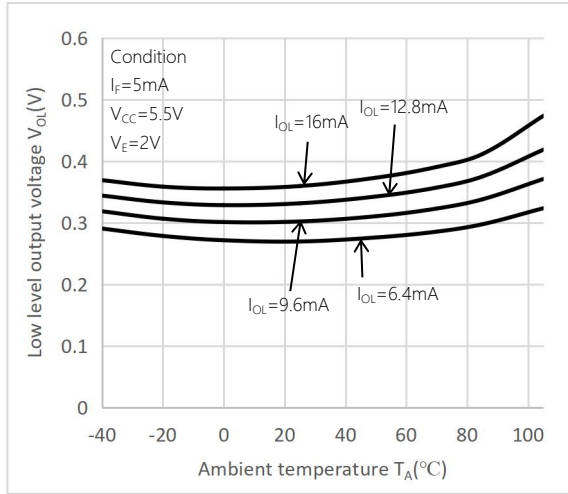


Fig.2 Forward current vs. Forward voltage

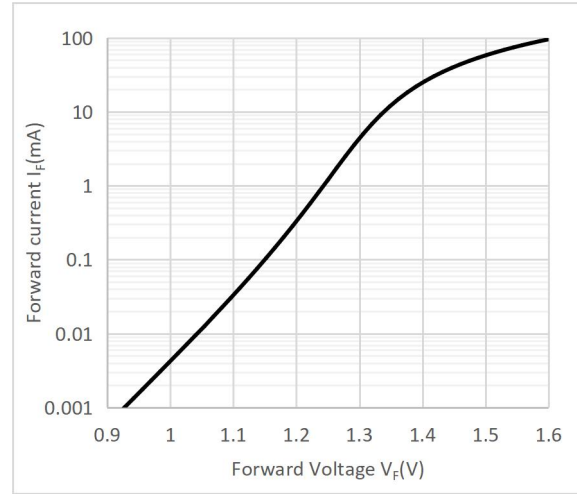


Fig.3 Propagation delay time vs. Forward current

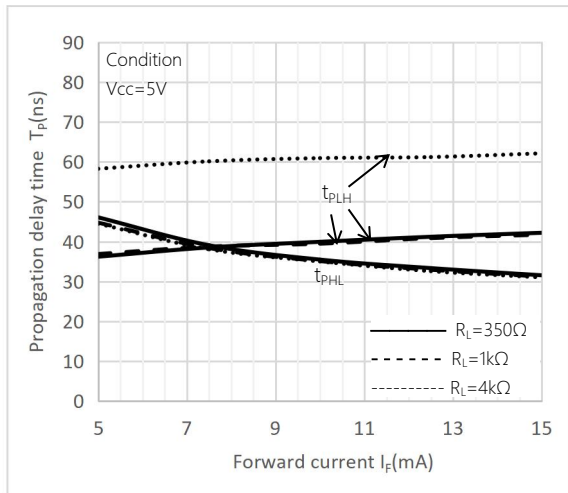


Fig.4 Low-level output current vs. Ambient temperature

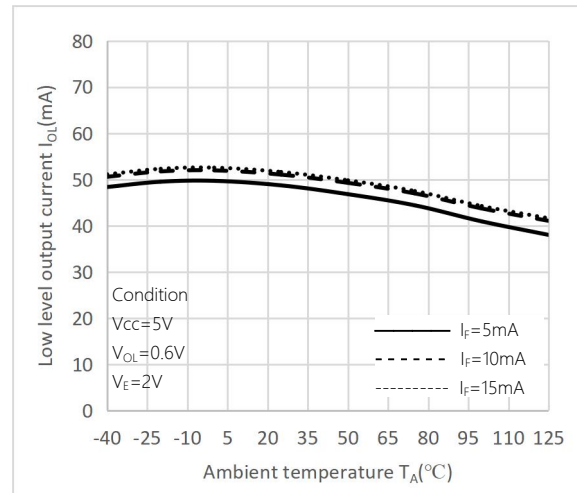


Fig.5 Input threshold current vs. Ambient temperature

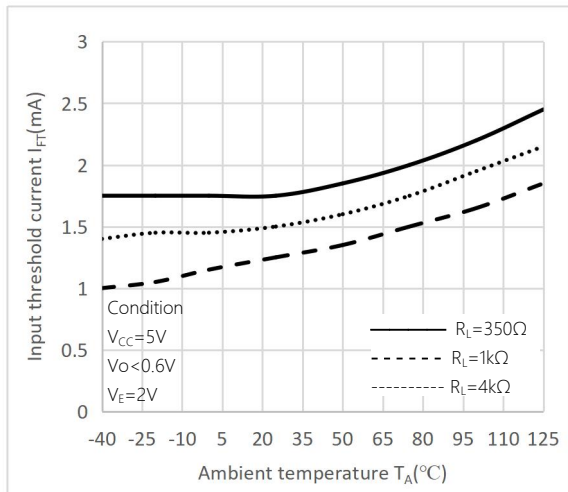


Fig.6 Output voltage vs. Forward current

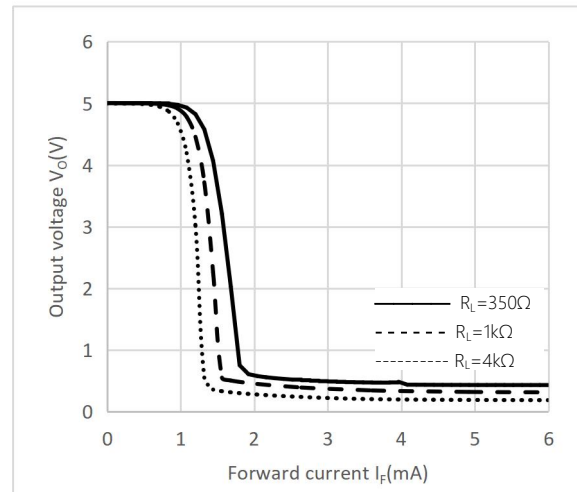


Fig.7 Pulse-width distortion vs. Ambient temperature

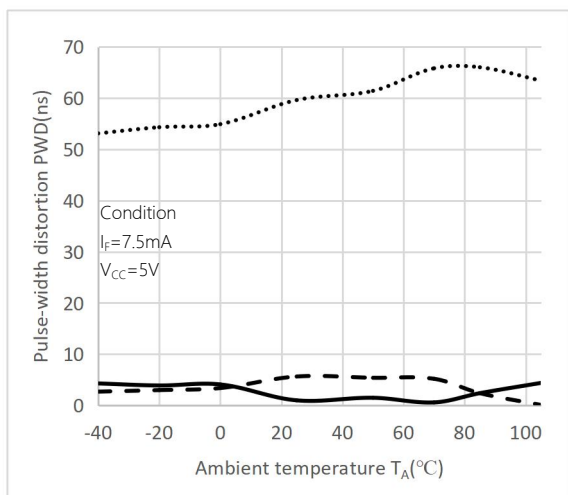


Fig.8 Switching time vs. Ambient temperature

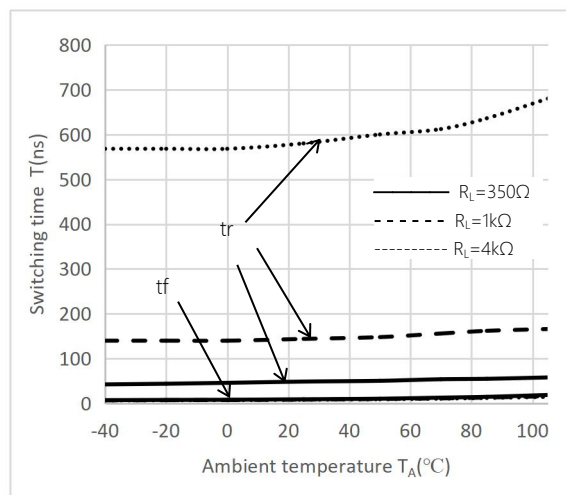


Fig.9 Propagation delay time vs. Ambient temperature

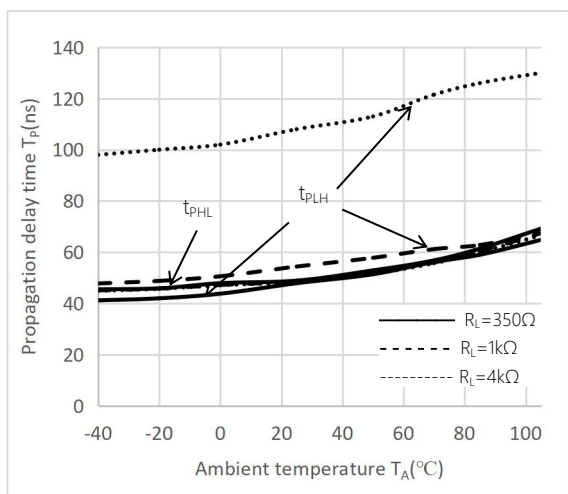


Fig.10 Enable propagation delay time vs. Ambient temperature

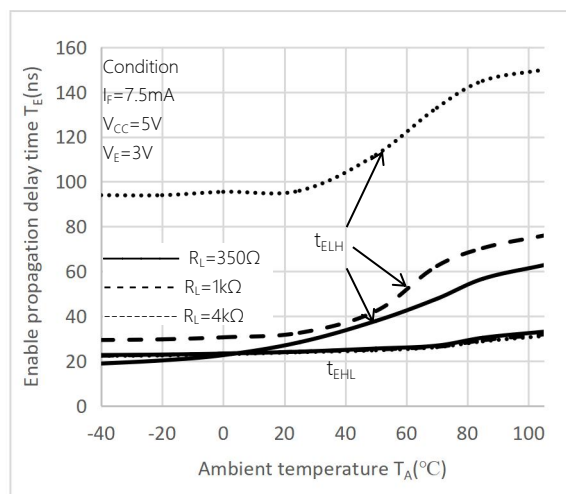
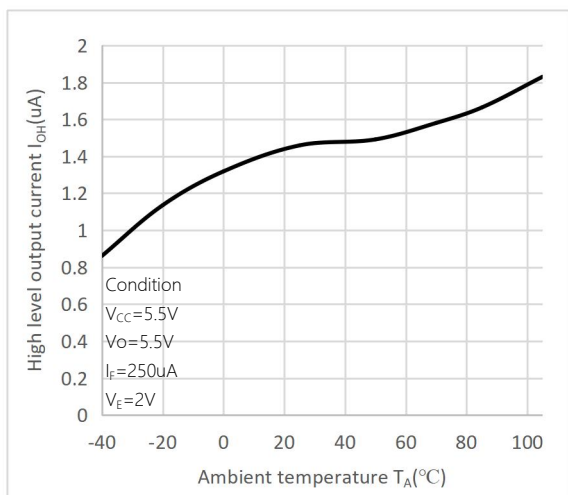
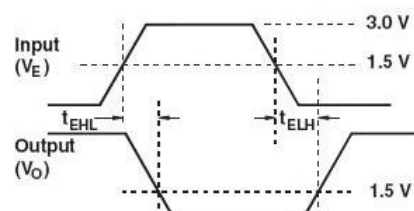
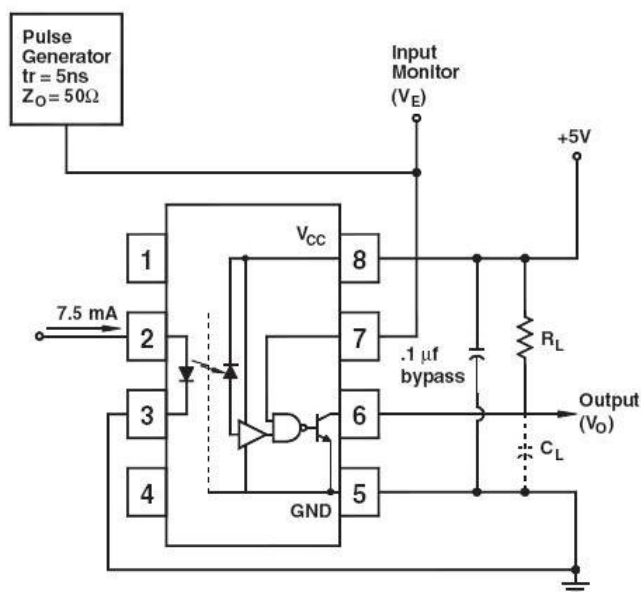
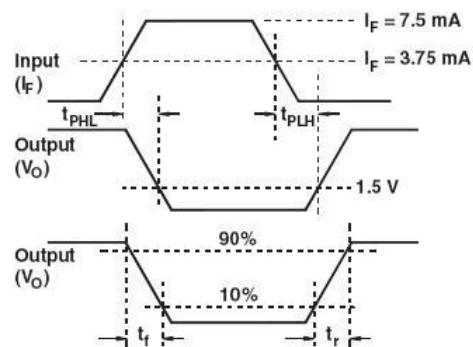
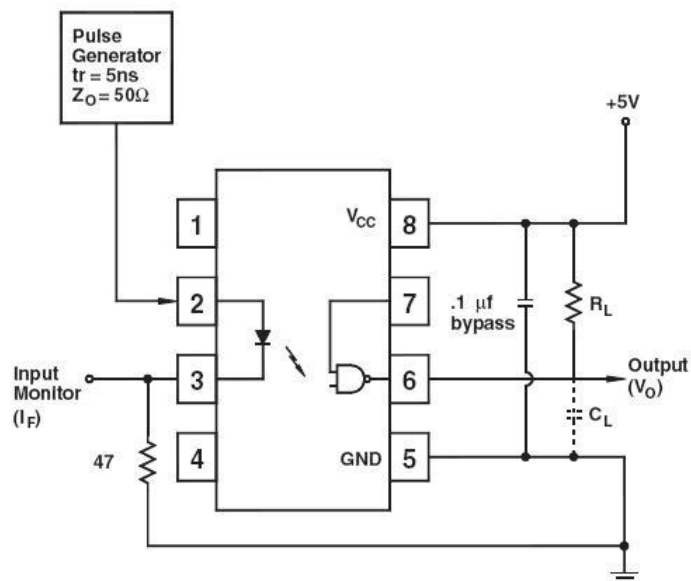


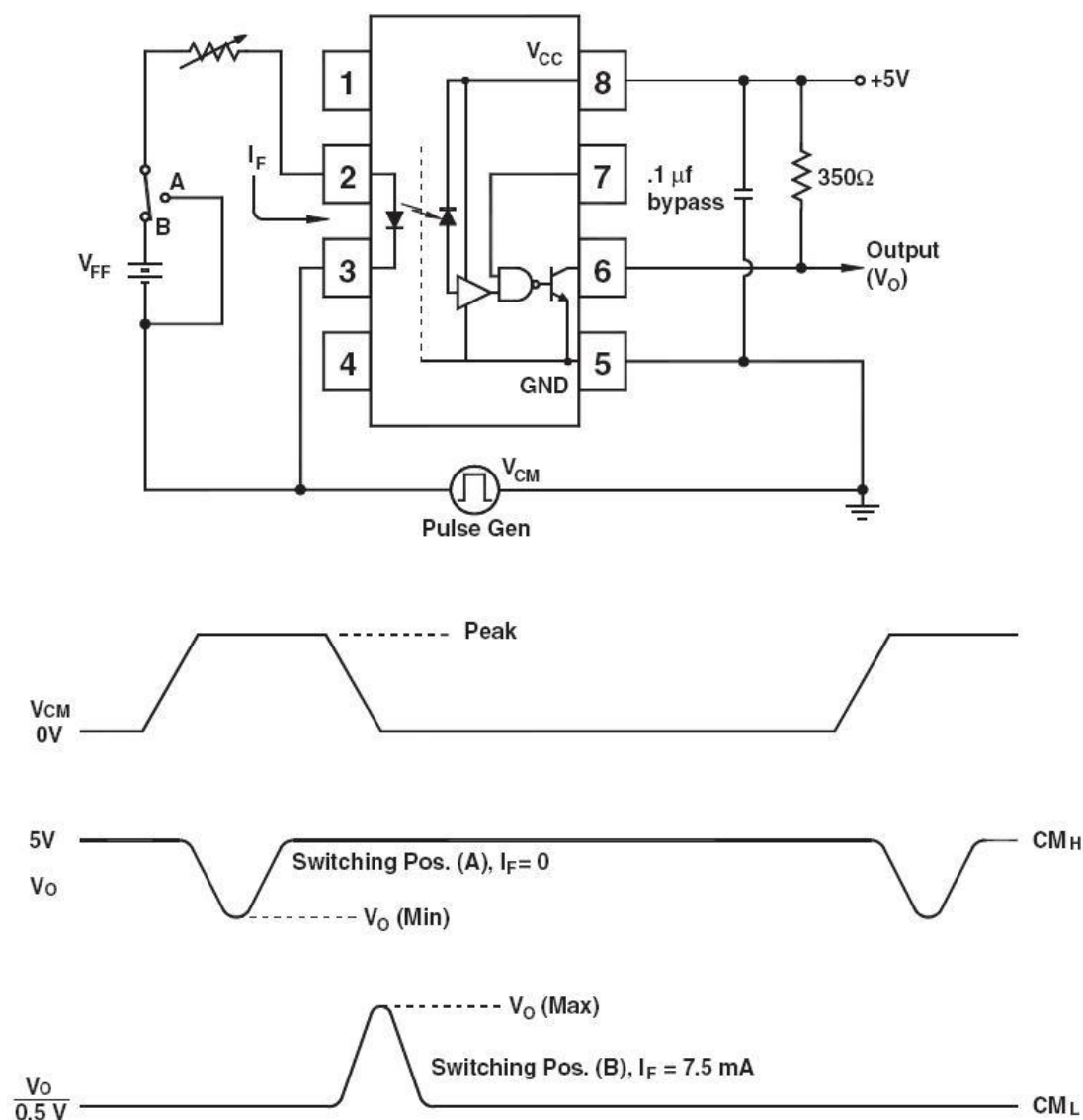
Fig.11 High-level output current vs. Ambient temperature



传输延迟时间测试电路 Test Circuit for Propagation Delay Time

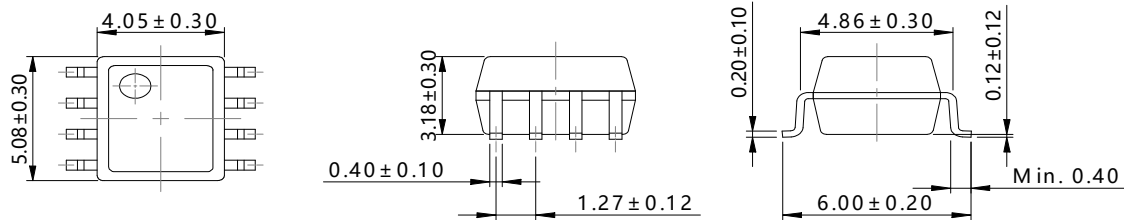


CMR 测试电路 Test Circuit for Common Mode Transient Immunity



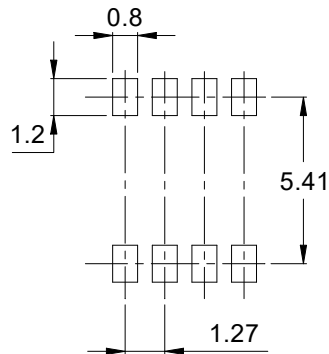
外形尺寸 Outline Dimensions

SOP8



单位 Unit: mm

建议焊盘布局 Recommended Pad Layout

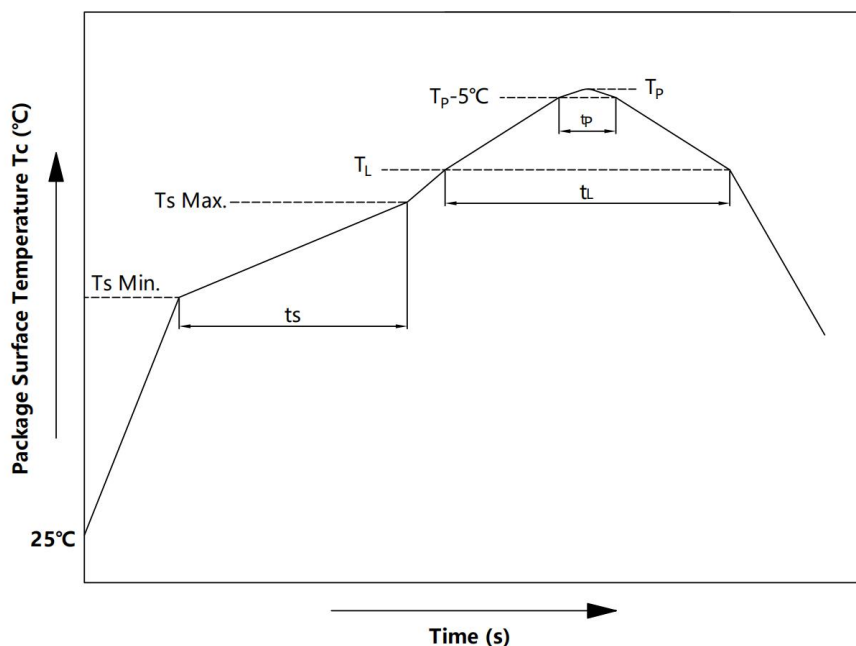


单位 Unit: mm

注：上图为产品正视图。

Note: The picture above is the front view of the product.

回流焊温度曲线图 Solder Reflow Profile



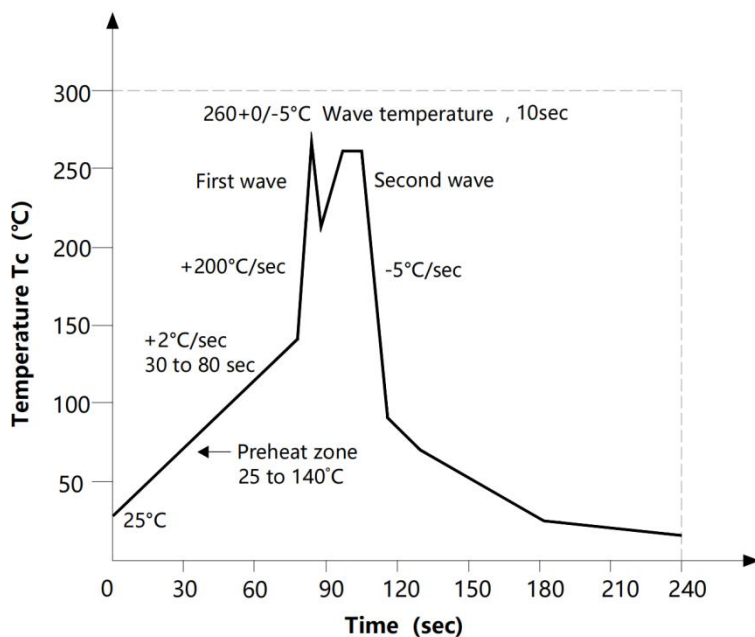
项目 Item	符号 Symbol	最小值 Min.	最大值 Max.	单位 Unit
预热温度 Preheat Temperature	T_s	150	200	$^{\circ}\text{C}$
预热时间 Preheat Time	t_s	60	120	s
升温速率 Ramp-Up Rate (T_L to T_P)	-	-	3	$^{\circ}\text{C/s}$
液相线温度 Liquidus Temperature	T_L	217		$^{\circ}\text{C}$
时间高于 T_L Time Above T_L	t_L	60	150	s
峰值温度 Peak Temperature	T_P	-	260	$^{\circ}\text{C}$
T_c 在 $(T_P - 5)$ 和 T_P 之间的时间 Time During Which T_c Is Between $(T_P - 5)$ and T_P	t_p	-	30	s
降温速率 Ramp-down Rate (T_P to T_L)	-	-	6	$^{\circ}\text{C/s}$

注 Note:

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

波峰焊温度曲线图 Wave Soldering Profile



手工烙铁焊接 Soldering with hand soldering iron

A. 手工烙铁焊仅用于产品返修或样品测试;

Hand soldering iron is only used for product rework or sample testing;

B. 手工烙铁焊要求: 温度 $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$, 时间 $\leq 3\text{s}$ 。

Hand soldering iron requirements: Temperature: $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$, within 3s.

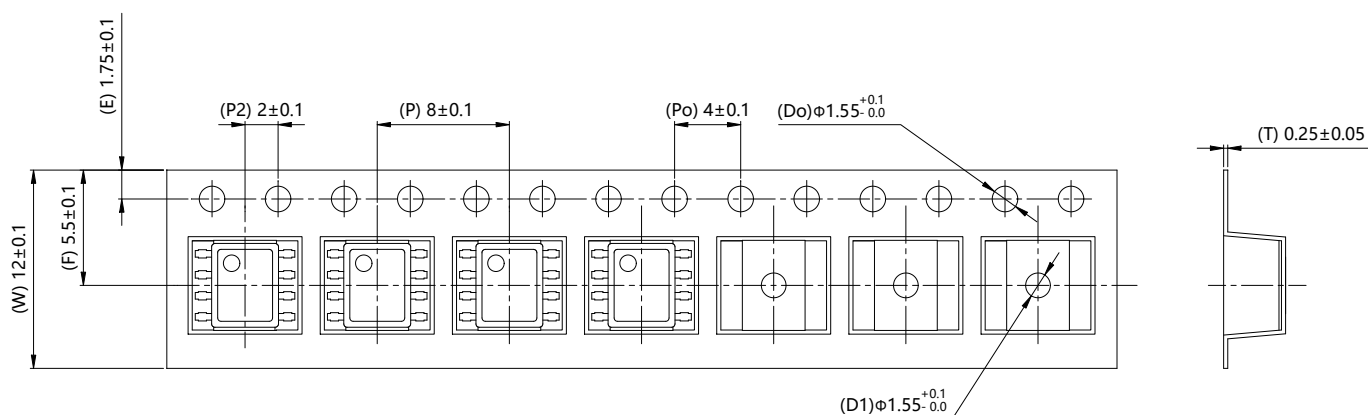
包装 Packing

■ 汇总表 Summary table

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
SOP8	编带 ($\phi 330\text{mm}$ 蓝盘)	2k /盘	2 盘/盒	10 盒/箱	450*390*0.1mm	353*340*60mm	650*375*365mm	首端各空 50 个 空格, 末端空 100
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
SOP8	Reel ($\phi 330\text{mm}$ Blue)	2k pcs/reel	2 reels /box	10 boxes /ctn	450*390*0.1mm	353*340*60mm	650*375*365mm	Leave 50 spaces at the beginning and 100 spaces at the end

■ 编带包装 Tape & Reel

- 1) 每卷数量: 2000 只。
Qty/reel: 2000 pcs.
- 2) 每箱数量: 40000 只。
Qty/ctn: 40000 pcs.
- 3) 内包装: 每盒 2 盘。
Inner packing: 2reels/box
- 4) 示意图 Schematic:



单位 Unit: mm

注意 Attention

- 群芯持续不断改进质量、可靠性、功能或设计，保留此产品更改的权利恕不另行通知。
QUNXIN continuously improve quality, reliability, function and design. We reserve the right to change this product without prior notice.
- 请遵守产品规格书使用，群芯不对使用时不符合产品规格书条件而导致的质量问题负责。
Please use in accordance with the product specification. QUNXIN is not responsible for the quality problems caused by non-compliance with the product specifications.
- 对于需要高可靠性或安全性的设备/装置需求，请联系我们的销售人员。
For equipment/devices requiring high reliability or safety, please contact our sales representatives.
- 当需要用于任何“特定”应用时，请咨询我们的销售人员。
When requiring a device for any “specific” application, please contact our sales in advice.
- 如对文件中表述的内容有疑问，欢迎联系我们。
If you have any questions about the contents of the document, please contact us.